NSN 5961-01-333-3387

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-333-3387 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.250 inches and 0.450 inches Overall Width: 1.050 inches **End Application:** Tactical air operations module an/tyq-2 (v) 1 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 180.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 25.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 12.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

NSN 5961-01-333-3387

Transistor - Page 2 of 2



_		••	• •				
וו	em	ш	112	rız	211	n	٠.

No

Fiig:

A110a0